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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

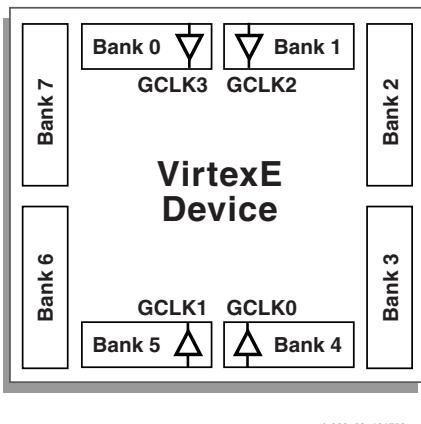
Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Obsolete
Number of LABs/CLBs	1536
Number of Logic Elements/Cells	6912
Total RAM Bits	131072
Number of I/O	158
Number of Gates	411955
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	240-BFQFP
Supplier Device Package	240-PQFP (32x32)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv300e-7pq240i

Eight I/O banks result from separating each edge of the FPGA into two banks, as shown in [Figure 3](#). Each bank has multiple V_{CCO} pins, all of which must be connected to the same voltage. This voltage is determined by the output standards in use.



[Figure 3: Virtex-E I/O Banks](#)

Within a bank, output standards can be mixed only if they use the same V_{CCO} . Compatible standards are shown in [Table 2](#). GTL and GTL+ appear under all voltages because their open-drain outputs do not depend on V_{CCO} .

[Table 2: Compatible Output Standards](#)

V_{CCO}	Compatible Standards
3.3 V	PCI, LVTTI, SSTL3 I, SSTL3 II, CTT, AGP, GTL, GTL+, LVPECL
2.5 V	SSTL2 I, SSTL2 II, LVCMOS2, GTL, GTL+, BLVDS, LVDS
1.8 V	LVCMOS18, GTL, GTL+
1.5 V	HSTL I, HSTL III, HSTL IV, GTL, GTL+

Some input standards require a user-supplied threshold voltage, V_{REF} . In this case, certain user-I/O pins are automatically configured as inputs for the V_{REF} voltage. Approximately one in six of the I/O pins in the bank assume this role.

The V_{REF} pins within a bank are interconnected internally and consequently only one V_{REF} voltage can be used within each bank. All V_{REF} pins in the bank, however, must be connected to the external voltage source for correct operation.

Within a bank, inputs that require V_{REF} can be mixed with those that do not. However, only one V_{REF} voltage can be used within a bank.

In Virtex-E, input buffers with LVTTI, LVCMOS2, LVCMOS18, PCI33_3, PCI66_3 standards are supplied by V_{CCO} rather than V_{CCINT} . For these standards, only input and output buffers that have the same V_{CCO} can be mixed together.

The V_{CCO} and V_{REF} pins for each bank appear in the device pin-out tables and diagrams. The diagrams also show the bank affiliation of each I/O.

Within a given package, the number of V_{REF} and V_{CCO} pins can vary depending on the size of device. In larger devices, more I/O pins convert to V_{REF} pins. Since these are always a super set of the V_{REF} pins used for smaller devices, it is possible to design a PCB that permits migration to a larger device if necessary. All the V_{REF} pins for the largest device anticipated must be connected to the V_{REF} voltage, and not used for I/O.

In smaller devices, some V_{CCO} pins used in larger devices do not connect within the package. These unconnected pins can be left unconnected externally, or can be connected to the V_{CCO} voltage to permit migration to a larger device if necessary.

Configurable Logic Blocks

The basic building block of the Virtex-E CLB is the logic cell (LC). An LC includes a 4-input function generator, carry logic, and a storage element. The output from the function generator in each LC drives both the CLB output and the D input of the flip-flop. Each Virtex-E CLB contains four LCs, organized in two similar slices, as shown in [Figure 4](#). [Figure 5](#) shows a more detailed view of a single slice.

In addition to the four basic LCs, the Virtex-E CLB contains logic that combines function generators to provide functions of five or six inputs. Consequently, when estimating the number of system gates provided by a given device, each CLB counts as 4.5 LCs.

Look-Up Tables

Virtex-E function generators are implemented as 4-input look-up tables (LUTs). In addition to operating as a function generator, each LUT can provide a 16 x 1-bit synchronous RAM. Furthermore, the two LUTs within a slice can be combined to create a 16 x 2-bit or 32 x 1-bit synchronous RAM, or a 16 x 1-bit dual-port synchronous RAM.

The Virtex-E LUT can also provide a 16-bit shift register that is ideal for capturing high-speed or burst-mode data. This mode can also be used to store data in applications such as Digital Signal Processing.

VHDL Initialization Example

The voltage reference signal is “banked” within the Virtex-E device on a half-edge basis such that for all packages there are eight independent V_{REF} banks internally. See [Figure 38](#) for a representation of the Virtex-E I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a V_{REF} input. After placing a differential amplifier input signal within a given V_{REF} bank, the same external source must drive all I/O pins configured as a V_{REF} input.

IBUF placement restrictions require that any differential amplifier input signals within a bank be of the same standard. How to specify a specific location for the IBUF via the LOC property is described below. [Table 19](#) summarizes the Virtex-E input standards compatibility requirements.

An optional delay element is associated with each IBUF. When the IBUF drives a flip-flop within the IOB, the delay element by default activates to ensure a zero hold-time requirement. The NODELAY=TRUE property overrides this default.

When the IBUF does not drive a flip-flop within the IOB, the delay element de-activates by default to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

Table 19: Xilinx Input Standards Compatibility Requirements

Rule 1	Standards with the same input V_{CCO} , output V_{CCO} , and V_{REF} can be placed within the same bank.
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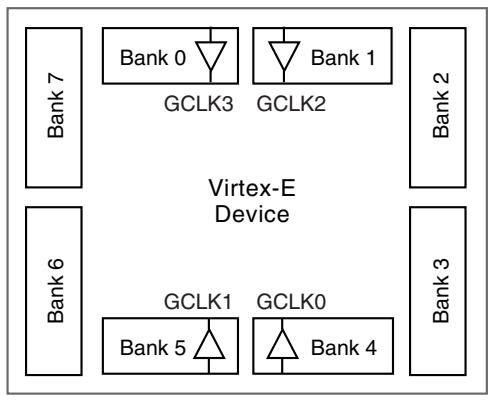


Figure 38: Virtex-E I/O Banks

IBUFG

Signals used as high fanout clock inputs to the Virtex-E device should drive a global clock input buffer (IBUFG) via an external input port in order to take advantage of one of the four dedicated global clock distribution networks. The output of the IBUFG should only drive a CLKDLL,

CLKDLLHF, or BUFG symbol. The generic Virtex-E IBUFG symbol appears in [Figure 39](#).

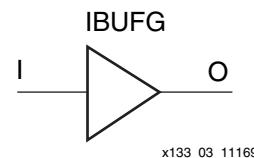


Figure 39: Virtex-E Global Clock Input Buffer (IBUFG) Symbol

The extension to the base name determines which I/O standard is used by the IBUFG. With no extension specified for the generic IBUFG symbol, the assumed standard is LVTTL.

The following list details variations of the IBUFG symbol.

- IBUFG
- IBUFG_LVCMOS2
- IBUFG_PCI33_3
- IBUFG_PCI66_3
- IBUFG_GTL
- IBUFG_GTLP
- IBUFG_HSTL_I
- IBUFG_HSTL_III
- IBUFG_HSTL_IV
- IBUFG_SSTL3_I
- IBUFG_SSTL3_II
- IBUFG_SSTL2_I
- IBUFG_SSTL2_II
- IBUFG_CTT
- IBUFG_AGP
- IBUFG_LVCMOS18
- IBUFG_LVDS
- IBUFG_LVPECL

When the IBUFG symbol supports an I/O standard that requires a differential amplifier input, the IBUFG automatically configures as a differential amplifier input buffer. The low-voltage I/O standards with a differential amplifier input require an external reference voltage input V_{REF} .

The voltage reference signal is “banked” within the Virtex-E device on a half-edge basis such that for all packages there are eight independent V_{REF} banks internally. See [Figure 38](#) for a representation of the Virtex-E I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a V_{REF} input. After placing a differential amplifier input signal within a given V_{REF} bank, the same external source must drive all I/O pins configured as a V_{REF} input.

IBUFG placement restrictions require any differential amplifier input signals within a bank be of the same standard. The LOC property can specify a location for the IBUFG.

As an added convenience, the BUFGP can be used to instantiate a high fanout clock input. The BUFGP symbol

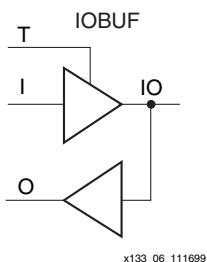


Figure 42: Input/Output Buffer Symbol (IOBUF)

The following list details variations of the IOBUF symbol.

- IOBUF
- IOBUF_S_2
- IOBUF_S_4
- IOBUF_S_6
- IOBUF_S_8
- IOBUF_S_12
- IOBUF_S_16
- IOBUF_S_24
- IOBUF_F_2
- IOBUF_F_4
- IOBUF_F_6
- IOBUF_F_8
- IOBUF_F_12
- IOBUF_F_16
- IOBUF_F_24
- IOBUF_LVCMOS2
- IOBUF_PCI33_3
- IOBUF_PCI66_3
- IOBUF_GTL
- IOBUF_GTL_P
- IOBUF_HSTL_I
- IOBUF_HSTL_III
- IOBUF_HSTL_IV
- IOBUF_SSTL3_I
- IOBUF_SSTL3_II
- IOBUF_SSTL2_I
- IOBUF_SSTL2_II
- IOBUF_CTT
- IOBUF_AGPA
- IOBUF_LVCMOS18
- IOBUF_LVDS
- IOBUF_LVPECL

When the IOBUF symbol used supports an I/O standard that requires a differential amplifier input, the IOBUF automatically configures with a differential amplifier input buffer.

The low-voltage I/O standards with a differential amplifier input require an external reference voltage input V_{REF} .

The voltage reference signal is “banked” within the Virtex-E device on a half-edge basis such that for all packages there are eight independent V_{REF} banks internally. See [Figure 38, page 34](#) for a representation of the Virtex-E I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a V_{REF} input. After placing a differential amplifier input signal within a given V_{REF} bank, the same external source must drive all I/O pins configured as a V_{REF} input.

IOBUF placement restrictions require any differential amplifier input signals within a bank be of the same standard.

The Virtex-E series supports eight banks for the HQ and PQ packages. The CS package supports four V_{CCO} banks.

Additional restrictions on the Virtex-E SelectI/O IOBUF placement require that within a given V_{CCO} bank each IOBUF must share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within the same V_{CCO} bank. The LOC property can specify a location for the IOBUF.

An optional delay element is associated with the input path in each IOBUF. When the IOBUF drives an input flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Override this default with the NODELAY=TRUE property.

In the case when the IOBUF does not drive an input flip-flop within the IOB, the delay element de-activates by default to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak “keeper” circuit. Control this feature by adding the appropriate symbol to the output net of the IOBUF (PULLUP, PULLDOWN, or KEEPER).

SelectI/O Properties

Access to some of the SelectI/O features (for example, location constraints, input delay, output drive strength, and slew rate) is available through properties associated with these features.

Input Delay Properties

An optional delay element is associated with each IBUF. When the IBUF drives a flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Use the NODELAY=TRUE property to override this default.

In the case when the IBUF does not drive a flip-flop within the IOB, the delay element by default de-activates to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

Table 44: Bidirectional I/O Library Macros

Name	Inputs	Bidirectional	Outputs
IOBUFDS_FD_LVDS	D, T, C	IO, IOB	Q
IOBUFDS_FDE_LVDS	D, T, CE, C	IO, IOB	Q
IOBUFDS_FDC_LVDS	D, T, C, CLR	IO, IOB	Q
IOBUFDS_FDCE_LVDS	D, T, CE, C, CLR	IO, IOB	Q
IOBUFDS_FDP_LVDS	D, T, C, PRE	IO, IOB	Q
IOBUFDS_FDPE_LVDS	D, T, CE, C, PRE	IO, IOB	Q
IOBUFDS_FDR_LVDS	D, T, C, R	IO, IOB	Q
IOBUFDS_FDRE_LVDS	D, T, CE, C, R	IO, IOB	Q
IOBUFDS_FDS_LVDS	D, T, C, S	IO, IOB	Q
IOBUFDS_FDSE_LVDS	D, T, CE, C, S	IO, IOB	Q
IOBUFDS_LD_LVDS	D, T, G	IO, IOB	Q
IOBUFDS_LDE_LVDS	D, T, GE, G	IO, IOB	Q
IOBUFDS_LDC_LVDS	D, T, G, CLR	IO, IOB	Q
IOBUFDS_LDCE_LVDS	D, T, GE, G, CLR	IO, IOB	Q
IOBUFDS_LDP_LVDS	D, T, G, PRE	IO, IOB	Q
IOBUFDS_LDPE_LVDS	D, T, GE, G, PRE	IO, IOB	Q

Revision History

The following table shows the revision history for this document.

Date	Version	Revision
12/7/99	1.0	Initial Xilinx release.
1/10/00	1.1	Re-released with spd.txt v. 1.18, FG860/900/1156 package information, and additional DLL, Select RAM and SelectI/O information.
1/28/00	1.2	Added Delay Measurement Methodology table, updated SelectI/O section, Figures 30, 54, & 55, text explaining Table 5, T_{BYP} values, buffered Hex Line info, p. 8, I/O Timing Measurement notes, notes for Tables 15, 16, and corrected F1156 pinout table footnote references.
2/29/00	1.3	Updated pinout tables, V_{CC} page 20, and corrected Figure 20.
5/23/00	1.4	Correction to table on p. 22.
7/10/00	1.5	<ul style="list-style-type: none"> • Numerous minor edits. • Data sheet upgraded to Preliminary. • Preview -8 numbers added to Virtex-E Electrical Characteristics tables.
8/1/00	1.6	<ul style="list-style-type: none"> • Reformatted entire document to follow new style guidelines. • Changed speed grade values in tables on pages 35-37.

Virtex-E Electrical Characteristics

Definition of Terms

Electrical and switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

Advance: These speed files are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

Preliminary: These speed files are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

Production: These speed files are released once enough production silicon of a particular device family member has been characterized to provide full correlation between speed files and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to Production before faster speed grades.

All specifications are representative of worst-case supply voltage and junction temperature conditions. The parameters included are common to popular designs and typical applications. Contact the factory for design considerations requiring more detailed information.

Table 1 correlates the current status of each Virtex-E device with a corresponding speed file designation.

Table 1: Virtex-E Device Speed Grade Designations

Device	Speed Grade Designations		
	Advance	Preliminary	Production
XCV50E			-8, -7, -6
XCV100E			-8, -7, -6
XCV200E			-8, -7, -6
XCV300E			-8, -7, -6
XCV400E			-8, -7, -6
XCV600E			-8, -7, -6
XCV1000E			-8, -7, -6
XCV1600E			-8, -7, -6
XCV2000E			-8, -7, -6
XCV2600E			-8, -7, -6
XCV3200E			-8, -7, -6

All specifications are subject to change without notice.

DC Characteristics

Absolute Maximum Ratings

Symbol	Description ⁽¹⁾		Units
V_{CCINT}	Internal Supply voltage relative to GND	-0.5 to 2.0	V
V_{CCO}	Supply voltage relative to GND	-0.5 to 4.0	V
V_{REF}	Input Reference Voltage	-0.5 to 4.0	V
$V_{IN}^{(3)}$	Input voltage relative to GND	-0.5 to $V_{CCO} + 0.5$	V
V_{TS}	Voltage applied to 3-state output	-0.5 to 4.0	V
V_{CC}	Longest Supply Voltage Rise Time from 0 V - 1.71 V	50	ms
T_{STG}	Storage temperature (ambient)	-65 to +150	°C
T_J	Junction temperature ⁽²⁾	Plastic packages +125	°C

Notes:

1. Stresses beyond those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those listed under Operating Conditions is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods of time can affect device reliability.
2. For soldering guidelines and thermal considerations, see the device packaging information on www.xilinx.com.
3. Inputs configured as PCI are fully PCI compliant. This statement takes precedence over any specification that would imply that the device is not PCI compliant.

Recommended Operating Conditions

Symbol	Description	Min	Max	Units	
V_{CCINT}	Internal Supply voltage relative to GND, $T_J = 0 \text{ }^{\circ}\text{C}$ to $+85 \text{ }^{\circ}\text{C}$	Commercial	1.8 – 5%	1.8 + 5%	V
	Internal Supply voltage relative to GND, $T_J = -40 \text{ }^{\circ}\text{C}$ to $+100 \text{ }^{\circ}\text{C}$	Industrial	1.8 – 5%	1.8 + 5%	V
V_{CCO}	Supply voltage relative to GND, $T_J = 0 \text{ }^{\circ}\text{C}$ to $+85 \text{ }^{\circ}\text{C}$	Commercial	1.2	3.6	V
	Supply voltage relative to GND, $T_J = -40 \text{ }^{\circ}\text{C}$ to $+100 \text{ }^{\circ}\text{C}$	Industrial	1.2	3.6	V
T_{IN}	Input signal transition time		250	ns	

IOB Output Switching Characteristics, Figure 1

Output delays terminating at a pad are specified for LVTTL with 12 mA drive and fast slew rate. For other standards, adjust the delays with the values shown in **IOB Output Switching Characteristics Standard Adjustments**, page 10.

		Speed Grade ⁽¹⁾				Units	
Description ⁽²⁾	Symbol	Min	-8	-7	-6		
Propagation Delays							
O input to Pad	T_{ILOOP}	1.04	2.5	2.7	2.9	ns, max	
O input to Pad via transparent latch	T_{IOOLP}	1.24	2.9	3.1	3.4	ns, max	
3-State Delays							
T input to Pad high-impedance (Note 2)	T_{IOTHZ}	0.73	1.5	1.7	1.9	ns, max	
T input to valid data on Pad	T_{IOTON}	1.13	2.7	2.9	3.1	ns, max	
T input to Pad high-impedance via transparent latch (Note 2)	$T_{IOTLPHZ}$	0.86	1.8	2.0	2.2	ns, max	
T input to valid data on Pad via transparent latch	$T_{IOTLPON}$	1.26	3.0	3.2	3.4	ns, max	
GTS to Pad high impedance (Note 2)	T_{GTS}	1.94	4.1	4.6	4.9	ns, max	
Sequential Delays							
Clock CLK							
Minimum Pulse Width, High	T_{CH}	0.56	1.2	1.3	1.4	ns, min	
Minimum Pulse Width, Low	T_{CL}	0.56	1.2	1.3	1.4	ns, min	
Clock CLK to Pad	T_{IOCKP}	0.97	2.4	2.8	2.9	ns, max	
Clock CLK to Pad high-impedance (synchronous) (Note 2)	T_{IOCKHZ}	0.77	1.6	2.0	2.2	ns, max	
Clock CLK to valid data on Pad (synchronous)	T_{IOCKON}	1.17	2.8	3.2	3.4	ns, max	
Setup and Hold Times before/after Clock CLK							
O input	T_{IOOCK} / T_{IOCKO}	0.43 / 0	0.9 / 0	1.0 / 0	1.1 / 0	ns, min	
OCE input	$T_{IOOCECK} / T_{IOOCKOCE}$	0.28 / 0	0.55 / 0.01	0.7 / 0	0.7 / 0	ns, min	
SR input (OFF)	$T_{IOSRCKO} / T_{IOCKOSR}$	0.40 / 0	0.8 / 0	0.9 / 0	1.0 / 0	ns, min	
3-State Setup Times, T input	T_{IOTCK} / T_{IOCKT}	0.26 / 0	0.51 / 0	0.6 / 0	0.7 / 0	ns, min	
3-State Setup Times, TCE input	$T_{IOTCECK} / T_{IOCKTCE}$	0.30 / 0	0.6 / 0	0.7 / 0	0.8 / 0	ns, min	
3-State Setup Times, SR input (TFF)	$T_{IOSRCKT} / T_{IOCKTSR}$	0.38 / 0	0.8 / 0	0.9 / 0	1.0 / 0	ns, min	
Set/Reset Delays							
SR input to Pad (asynchronous)	T_{IOSRP}	1.30	3.1	3.3	3.5	ns, max	
SR input to Pad high-impedance (asynchronous) (Note 2)	T_{IOSRHZ}	1.08	2.2	2.4	2.7	ns, max	
SR input to valid data on Pad (asynchronous)	T_{IOSRON}	1.48	3.4	3.7	3.9	ns, max	
GSR to Pad	T_{IOGSRQ}	3.88	7.6	8.5	9.7	ns, max	

Notes:

1. A Zero "0" Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed "best-case", but if a "0" is listed, there is no positive hold time.
2. 3-state turn-off delays should not be adjusted.

IOB Output Switching Characteristics Standard Adjustments

Output delays terminating at a pad are specified for LVTTL with 12 mA drive and fast slew rate. For other standards, adjust the delays by the values shown.

Description	Symbol	Standard	Speed Grade				Units
			Min	-8	-7	-6	
Output Delay Adjustments							
Standard-specific adjustments for output delays terminating at pads (based on standard capacitive load, C _{SL})	T _{OLVTTL_S2}	LVTTL, Slow, 2 mA	4.2	+14.7	+14.7	+14.7	ns
	T _{OLVTTL_S4}	4 mA	2.5	+7.5	+7.5	+7.5	ns
	T _{OLVTTL_S6}	6 mA	1.8	+4.8	+4.8	+4.8	ns
	T _{OLVTTL_S8}	8 mA	1.2	+3.0	+3.0	+3.0	ns
	T _{OLVTTL_S12}	12 mA	1.0	+1.9	+1.9	+1.9	ns
	T _{OLVTTL_S16}	16 mA	0.9	+1.7	+1.7	+1.7	ns
	T _{OLVTTL_S24}	24 mA	0.8	+1.3	+1.3	+1.3	ns
	T _{OLVTTL_F2}	LVTTL, Fast, 2 mA	1.9	+13.1	+13.1	+13.1	ns
	T _{OLVTTL_F4}	4 mA	0.7	+5.3	+5.3	+5.3	ns
	T _{OLVTTL_F6}	6 mA	0.20	+3.1	+3.1	+3.1	ns
	T _{OLVTTL_F8}	8 mA	0.10	+1.0	+1.0	+1.0	ns
	T _{OLVTTL_F12}	12 mA	0.0	0.0	0.0	0.0	ns
	T _{OLVTTL_F16}	16 mA	-0.10	-0.05	-0.05	-0.05	ns
	T _{OLVTTL_F24}	24 mA	-0.10	-0.20	-0.20	-0.20	ns
	T _{OLVCMOS_2}	LVCMOS2	0.10	+0.09	+0.09	+0.09	ns
	T _{OLVCMOS_18}	LVCMOS18	0.10	+0.7	+0.7	+0.7	ns
	T _{OLVDS}	LVDS	-0.39	-1.2	-1.2	-1.2	ns
	T _{OLVPECL}	LVPECL	-0.20	-0.41	-0.41	-0.41	ns
	T _{OPCI33_3}	PCI, 33 MHz, 3.3 V	0.50	+2.3	+2.3	+2.3	ns
	T _{OPCI66_3}	PCI, 66 MHz, 3.3 V	0.10	-0.41	-0.41	-0.41	ns
	T _{O GTL}	GTL	0.6	+0.49	+0.49	+0.49	ns
	T _{O GTLP}	GTL+	0.7	+0.8	+0.8	+0.8	ns
	T _{O HSTL_I}	HSTL I	0.10	-0.51	-0.51	-0.51	ns
	T _{O HSTL_III}	HSTL III	-0.10	-0.91	-0.91	-0.91	ns
	T _{O HSTL_IV}	HSTL IV	-0.20	-1.01	-1.01	-1.01	ns
	T _{O SSTL2_I}	SSTL2 I	-0.10	-0.51	-0.51	-0.51	ns
	T _{O SSTL2_II}	SSTL2 II	-0.20	-0.91	-0.91	-0.91	ns
	T _{O SSTL3_I}	SSTL3 I	-0.20	-0.51	-0.51	-0.51	ns
	T _{O SSTL3_II}	SSTL3 II	-0.30	-1.01	-1.01	-1.01	ns
	T _{O CTT}	CTT	0.0	-0.61	-0.61	-0.61	ns
	T _{O AGP}	AGP	-0.1	-0.91	-0.91	-0.91	ns

CLB Switching Characteristics

Delays originating at F/G inputs vary slightly according to the input used, see [Figure 2](#). The values listed below are worst-case. Precise values are provided by the timing analyzer.

Description	Symbol	Speed Grade⁽¹⁾				Units
		Min	-8	-7	-6	
Combinatorial Delays						
4-input function: F/G inputs to X/Y outputs	T_{ILO}	0.19	0.40	0.42	0.47	ns, max
5-input function: F/G inputs to F5 output	T_{IF5}	0.36	0.76	0.8	0.9	ns, max
5-input function: F/G inputs to X output	T_{IF5X}	0.35	0.74	0.8	0.9	ns, max
6-input function: F/G inputs to Y output via F6 MUX	T_{IF6Y}	0.35	0.74	0.9	1.0	ns, max
6-input function: F5IN input to Y output	T_{F5INY}	0.04	0.11	0.20	0.22	ns, max
Incremental delay routing through transparent latch to XQ/YQ outputs	T_{IFNCTL}	0.27	0.63	0.7	0.8	ns, max
BY input to YB output	T_{BYYB}	0.19	0.38	0.46	0.51	ns, max
Sequential Delays						
FF Clock CLK to XQ/YQ outputs	T_{CKO}	0.34	0.78	0.9	1.0	ns, max
Latch Clock CLK to XQ/YQ outputs	T_{CKLO}	0.40	0.77	0.9	1.0	ns, max
Setup and Hold Times before/after Clock CLK						
4-input function: F/G Inputs	T_{ICK} / T_{CKI}	0.39 / 0	0.9 / 0	1.0 / 0	1.1 / 0	ns, min
5-input function: F/G inputs	T_{IF5CK} / T_{CKIF5}	0.55 / 0	1.3 / 0	1.4 / 0	1.5 / 0	ns, min
6-input function: F5IN input	T_{F5INCK} / T_{CKF5IN}	0.27 / 0	0.6 / 0	0.8 / 0	0.8 / 0	ns, min
6-input function: F/G inputs via F6 MUX	T_{IF6CK} / T_{CKIF6}	0.58 / 0	1.3 / 0	1.5 / 0	1.6 / 0	ns, min
BX/BY inputs	T_{DICK} / T_{CKDI}	0.25 / 0	0.6 / 0	0.7 / 0	0.8 / 0	ns, min
CE input	T_{CECK} / T_{CKCE}	0.28 / 0	0.55 / 0	0.7 / 0	0.7 / 0	ns, min
SR/BY inputs (synchronous)	T_{RCK} / T_{CKR}	0.24 / 0	0.46 / 0	0.52 / 0	0.6 / 0	ns, min
Clock CLK						
Minimum Pulse Width, High	T_{CH}	0.56	1.2	1.3	1.4	ns, min
Minimum Pulse Width, Low	T_{CL}	0.56	1.2	1.3	1.4	ns, min
Set/Reset						
Minimum Pulse Width, SR/BY inputs	T_{RPW}	0.94	1.9	2.1	2.4	ns, min
Delay from SR/BY inputs to XQ/YQ outputs (asynchronous)	T_{RQ}	0.39	0.8	0.9	1.0	ns, max
Toggle Frequency (MHz) (for export control)	F_{TOG}	-	416	400	357	MHz

Notes:

1. A Zero "0" Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed "best-case", but if a "0" is listed, there is no positive hold time.

Virtex-E Pin-to-Pin Input Parameter Guidelines

All devices are 100% functionally tested. Listed below are representative values for typical pin locations and normal clock loading. Values are expressed in nanoseconds unless otherwise noted.

Global Clock Set-Up and Hold for LVTTL Standard, with DLL

Description ⁽¹⁾	Symbol	Device	Speed Grade ^(2, 3)				Units
			Min	-8	-7	-6	
Input Setup and Hold Time Relative to Global Clock Input Signal for LVTTL Standard. For data input with different standards, adjust the setup time delay by the values shown in IOB Input Switching Characteristics Standard Adjustments , page 8.							
No Delay Global Clock and IFF, with DLL	T_{PSDLL}/T_{PHDLL}	XCV50E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV100E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV200E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV300E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV400E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV600E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV1000E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV1600E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV2000E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV2600E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns
		XCV3200E	1.5 / -0.4	1.5 / -0.4	1.6 / -0.4	1.7 / -0.4	ns

Notes:

1. IFF = Input Flip-Flop or Latch
2. Setup time is measured relative to the Global Clock input signal with the fastest route and the lightest load. Hold time is measured relative to the Global Clock input signal with the slowest route and heaviest load.
3. DLL output jitter is already included in the timing calculation.

Table 14: BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin#	See Note
NA	GND	A29	
NA	GND	A32	
NA	GND	A33	
NA	GND	B1	
NA	GND	B6	
NA	GND	B9	
NA	GND	B15	
NA	GND	B23	
NA	GND	B27	
NA	GND	B31	
NA	GND	C2	
NA	GND	E1	
NA	GND	F32	
NA	GND	G2	
NA	GND	G33	
NA	GND	J32	
NA	GND	K1	
NA	GND	L2	
NA	GND	M33	
NA	GND	P1	
NA	GND	P33	
NA	GND	R32	
NA	GND	T1	
NA	GND	V33	
NA	GND	W2	
NA	GND	Y1	
NA	GND	Y33	
NA	GND	AB1	
NA	GND	AC32	
NA	GND	AD33	
NA	GND	AE2	
NA	GND	AG1	
NA	GND	AG32	
NA	GND	AH2	
NA	GND	AJ33	

Table 14: BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin#	See Note
NA	GND	AL32	
NA	GND	AM3	
NA	GND	AM7	
NA	GND	AM11	
NA	GND	AM19	
NA	GND	AM25	
NA	GND	AM28	
NA	GND	AM33	
NA	GND	AN1	
NA	GND	AN2	
NA	GND	AN5	
NA	GND	AN10	
NA	GND	AN14	
NA	GND	AN16	
NA	GND	AN20	
NA	GND	AN22	
NA	GND	AN27	
NA	GND	AN33	

Notes:

1. V_{REF} or I/O option only in the XCV2000E; otherwise, I/O option only.
2. V_{REF} or I/O option only in the XCV1600E & 2000E; otherwise, I/O option only.
3. V_{REF} or I/O option only in the XCV1000E, 1600E, & 2000E; otherwise, I/O option only.
4. V_{REF} or I/O option only in the XCV600E, 1000E, 1600E, & 2000E; otherwise, I/O option only.

Table 18: FG456 — XCV200E and XCV300E

Bank	Pin Description	Pin #
3	IO_L50N_YY	P19
3	IO_L51P_YY	P18
3	IO_D5_L51N_YY	R21
3	IO_D6_L52P_Y	T22
3	IO_VREF_L52N_Y	R19
3	IO_L53P_Y	U22
3	IO_L53N_Y	R18
3	IO_L54P_YY	T21
3	IO_L54N_YY	V22
3	IO_L55P_YY	T20
3	IO_VREF_L55N_YY	U21
3	IO_L56P_YY	W22
3	IO_L56N_YY	T18
3	IO_L57P_YY	U19
3	IO_VREF_L57N_YY	U20
3	IO_L58P_YY	W21
3	IO_L58N_YY	AA22
3	IO_D7_L59P_YY	Y21
3	IO_INIT_L59N_YY	V19
3	IO	M22
4	GCK0	W12
4	IO	W14
4	IO	Y13
4	IO	Y17
4	IO	AA16 ¹
4	IO	AA19
4	IO	AB12 ¹
4	IO	AB17
4	IO	AB21 ¹
4	IO_L60P_YY	W18
4	IO_L60N_YY	AA20
4	IO_L61P	Y18
4	IO_L61N	V17
4	IO_VREF_L62P_YY	AB20
4	IO_L62N_YY	W17
4	IO_L63P	AA18

Table 18: FG456 — XCV200E and XCV300E

Bank	Pin Description	Pin #
4	IO_L63N	V16
4	IO_VREF_L64P_YY	AB19
4	IO_L64N_YY	AB18
4	IO_L65P_Y	W16
4	IO_L65N_Y	AA17
4	IO_L66P_Y	Y16
4	IO_L66N_Y	V15
4	IO_VREF_L67P_YY	AB16
4	IO_L67N_YY	Y15
4	IO_L68P_YY	AA15
4	IO_L68N_YY	AB15
4	IO_L69P_Y	W15
4	IO_L69N_Y	Y14
4	IO_L70P_Y	V14
4	IO_L70N_Y	AA14
4	IO_L71P	AB14
4	IO_L71N	V13
4	IO_VREF_L72P_YY	AA13
4	IO_L72N_YY	AB13
4	IO_L73P_Y	W13
4	IO_L73N_Y	AA12
4	IO_L74P_Y	Y12
4	IO_L74N_Y	V12
4	IO_LVDS_DLL_L75P	U12
5	IO	U11 ¹
5	IO	V8
5	IO	W5
5	IO	AA3 ¹
5	IO	AA9
5	IO	AA10
5	IO	AB4
5	IO	AB7 ¹
5	IO	AB8
5	GCK1	Y11
5	IO_LVDS_DLL_L75N	AA11
5	IO_L76P_Y	AB11

Table 20: FG676 — XCV400E, XCV600E

Bank	Pin Description	Pin #
1	IO_L40P_YY	D20
1	IO_L41N_YY	F19
1	IO_VREF_L41P_YY	C21
1	IO_L42N_YY	B22
1	IO_L42P_YY	E20
1	IO_L43N_Y	A23
1	IO_L43P_Y	D21
1	IO_WRITE_L44N_YY	C22
1	IO_CS_L44P_YY	E21
2	IO	D25 ¹
2	IO	D26
2	IO	E26
2	IO	F26
2	IO	H26 ¹
2	IO	K26 ¹
2	IO	M25 ¹
2	IO	N26 ¹
2	IO_D1	K24
2	IO_DOUT_BUSY_L45P_YY	E23
2	IO_DIN_D0_L45N_YY	F22
2	IO_L46P_YY	E24
2	IO_L46N_YY	F20
2	IO_L47P_Y	G21
2	IO_L47N_Y	G22
2	IO_VREF_L48P_Y	F24
2	IO_L48N_Y	H20
2	IO_L49P_Y	E25
2	IO_L49N_Y	H21
2	IO_L50P_YY	F23
2	IO_L50N_YY	G23
2	IO_VREF_L51P_YY	H23
2	IO_L51N_YY	J20
2	IO_L52P_YY	G24
2	IO_L52N_YY	H22
2	IO_L53P_Y	J21
2	IO_L53N_Y	G25

Table 20: FG676 — XCV400E, XCV600E

Bank	Pin Description	Pin #
2	IO_VREF_L54P_Y	G26 ²
2	IO_L54N_Y	J22
2	IO_L55P_YY	H24
2	IO_L55N_YY	J23
2	IO_L56P_YY	J24
2	IO_VREF_L56N_YY	K20
2	IO_D2_L57P_YY	K22
2	IO_L57N_YY	K21
2	IO_L58P_YY	H25
2	IO_L58N_YY	K23
2	IO_L59P_Y	L20
2	IO_L59N_Y	J26
2	IO_L60P_Y	K25
2	IO_L60N_Y	L22
2	IO_L61P_Y	L21
2	IO_L61N_Y	L23
2	IO_L62P_Y	M20
2	IO_L62N_Y	L24
2	IO_VREF_L63P_YY	M23
2	IO_D3_L63N_YY	M22
2	IO_L64P_YY	L26
2	IO_L64N_YY	M21
2	IO_L65P_Y	N19
2	IO_L65N_Y	M24
2	IO_VREF_L66P_Y	M26
2	IO_L66N_Y	N20
2	IO_L67P_YY	N24
2	IO_L67N_YY	N21
2	IO_L68P_YY	N23
2	IO_L68N_YY	N22
3	IO	P24
3	IO	P26 ¹
3	IO	R26 ¹
3	IO	T26 ¹
3	IO	U26 ¹
3	IO	W25

Table 20: FG676 — XCV400E, XCV600E

Bank	Pin Description	Pin #
NA	NC	L2
NA	NC	F6
NA	NC	F25
NA	NC	F21
NA	NC	F2
NA	NC	C26
NA	NC	C25
NA	NC	C2
NA	NC	C1
NA	NC	B6
NA	NC	B26
NA	NC	B24
NA	NC	B21
NA	NC	B16
NA	NC	B11
NA	NC	B1
NA	NC	AF25
NA	NC	AF24
NA	NC	AF2
NA	NC	AE6
NA	NC	AE3
NA	NC	AE26
NA	NC	AE24
NA	NC	AE21
NA	NC	AE16
NA	NC	AE14
NA	NC	AE11
NA	NC	AE1
NA	NC	AD25
NA	NC	AD2
NA	NC	AD1
NA	NC	AA6
NA	NC	AA25
NA	NC	AA21
NA	NC	AA2
NA	NC	A3
NA	NC	A25

Table 20: FG676 — XCV400E, XCV600E

Bank	Pin Description	Pin #
NA	NC	A2
NA	NC	A15
NA	VCCINT	G7
NA	VCCINT	G20
NA	VCCINT	H8
NA	VCCINT	H19
NA	VCCINT	J9
NA	VCCINT	J10
NA	VCCINT	J11
NA	VCCINT	J16
NA	VCCINT	J17
NA	VCCINT	J18
NA	VCCINT	K9
NA	VCCINT	K18
NA	VCCINT	L9
NA	VCCINT	L18
NA	VCCINT	T9
NA	VCCINT	T18
NA	VCCINT	U9
NA	VCCINT	U18
NA	VCCINT	V9
NA	VCCINT	V10
NA	VCCINT	V11
NA	VCCINT	V16
NA	VCCINT	V17
NA	VCCINT	V18
NA	VCCINT	Y7
NA	VCCINT	Y20
NA	VCCINT	W8
NA	VCCINT	W19
0	VCCO	J13
0	VCCO	J12
0	VCCO	H9
0	VCCO	H12
0	VCCO	H11

**Table 21: FG676 Differential Pin Pair Summary
XCV400E, XCV600E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
52	2	G24	H22	✓	-
53	2	J21	G25	2	-
54	2	G26	J22	1	VREF
55	2	H24	J23	✓	-
56	2	J24	K20	✓	VREF
57	2	K22	K21	✓	D2
58	2	H25	K23	✓	-
59	2	L20	J26	2	-
60	2	K25	L22	1	-
61	2	L21	L23	1	-
62	2	M20	L24	1	-
63	2	M23	M22	✓	D3
64	2	L26	M21	✓	-
65	2	N19	M24	2	-
66	2	M26	N20	1	VREF
67	2	N24	N21	✓	-
68	2	N23	N22	✓	-
69	3	P21	P23	✓	-
70	3	P22	R25	1	VREF
71	3	P19	P20	2	-
72	3	R21	R22	✓	-
73	3	R24	R23	✓	VREF
74	3	T24	R20	1	-
75	3	T22	U24	1	-
76	3	T23	U25	1	-
77	3	T21	U20	2	-
78	3	U22	V26	✓	-
79	3	T20	U23	✓	D5
80	3	V24	U21	✓	VREF
81	3	V23	W24	✓	-
82	3	V22	W26	1	VREF
83	3	Y25	V21	2	-
84	3	V20	AA26	✓	-
85	3	Y24	W23	✓	VREF

**Table 21: FG676 Differential Pin Pair Summary
XCV400E, XCV600E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
86	3	AA24	Y23	1	-
87	3	AB26	W21	2	-
88	3	Y22	W22	1	VREF
89	3	AA23	AB24	2	-
90	3	W20	AC24	✓	-
91	3	AB23	Y21	✓	INIT
92	4	AC22	AD26	✓	-
93	4	AD23	AA20	1	-
94	4	Y19	AC21	✓	-
95	4	AD22	AB20	✓	VREF
96	4	AE22	Y18	NA	-
97	4	AF22	AA19	NA	-
98	4	AD21	AB19	✓	VREF
99	4	AC20	AA18	✓	-
100	4	AC19	AD20	1	-
101	4	AF20	AB18	1	VREF
102	4	AD19	Y17	NA	-
103	4	AE19	AD18	NA	VREF
104	4	AF19	AA17	✓	-
105	4	AC17	AB17	1	-
106	4	Y16	AE17	✓	-
107	4	AF17	AA16	✓	-
108	4	AD17	AB16	NA	-
109	4	AC16	AD16	✓	-
110	4	AC15	Y15	✓	VREF
111	4	AD15	AA15	✓	-
112	4	W14	AB15	1	-
113	4	AF15	Y14	1	VREF
114	4	AD14	AB14	NA	-
115	5	AC14	AF13	NA	IO_LVDS_DLL
116	5	AA13	AF12	1	VREF
117	5	AC13	W13	1	-
118	5	AA12	AD12	✓	-
119	5	AC12	AB12	✓	VREF

Table 22: FG680-XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
7	IO_L234N_YY	K38
7	IO_L234P_YY	L37
7	IO_L235N_YY	J39
7	IO_VREF_L235P_YY	L36
7	IO_L236N	J38
7	IO_L236P	K37
7	IO_L237N	H39
7	IO_VREF_L237P	K36 ³
7	IO_L238N_YY	H38
7	IO_L238P_YY	J37
7	IO_L239N_YY	G39
7	IO_VREF_L239P_YY	G38
7	IO_L240N_Y	J36
7	IO_L240P_Y	F39
7	IO_L241N	H37
7	IO_L241P	F38
7	IO_L242N_YY	H36
7	IO_L242P_YY	E39
7	IO_L243N_Y	G37
7	IO_VREF_L243P_Y	E38
7	IO_L244N	G36
7	IO_L244P	D39
7	IO_L245N	D38
7	IO_VREF_L245P	F36 ¹
7	IO_L246N_Y	D37
7	IO_L246P_Y	E37
<hr/>		
2	CCLK	E4
3	DONE	AU5
NA	DXN	AV37
NA	DXP	AU35
NA	M0	AT37
NA	M1	AU38
NA	M2	AT35
NA	PROGRAM	AT5
NA	TCK	C36

Table 22: FG680-XCV600E, XCV1000E, XCV1600E, XCV2000E

Bank	Pin Description	Pin #
NA	TDI	B3
2	TDO	C4
NA	TMS	E36
<hr/>		
NA	VCCINT	E8
NA	VCCINT	E9
NA	VCCINT	E15
NA	VCCINT	E16
NA	VCCINT	E24
NA	VCCINT	E25
NA	VCCINT	E31
NA	VCCINT	E32
NA	VCCINT	H5
NA	VCCINT	H35
NA	VCCINT	J5
NA	VCCINT	J35
NA	VCCINT	R5
NA	VCCINT	R35
NA	VCCINT	T5
NA	VCCINT	T35
NA	VCCINT	AD5
NA	VCCINT	AD35
NA	VCCINT	AE5
NA	VCCINT	AE35
NA	VCCINT	AL5
NA	VCCINT	AL35
NA	VCCINT	AM5
NA	VCCINT	AM35
NA	VCCINT	AR8
NA	VCCINT	AR9
NA	VCCINT	AR15
NA	VCCINT	AR16
NA	VCCINT	AR24
NA	VCCINT	AR25
NA	VCCINT	AR31
NA	VCCINT	AR32

Table 23: FG680 Differential Pin Pair Summary
XCV600E, XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
120	3	AN4	AT1	4	-
121	3	AR2	AP4	4	VREF
122	3	AT2	AR3	6	-
123	3	AR4	AU2	✓	INIT
124	4	AU4	AV5	✓	-
125	4	AT6	AV4	5	-
126	4	AU6	AW4	5	VREF
127	4	AT7	AW5	✓	-
128	4	AU7	AV6	✓	VREF
129	4	AT8	AW6	3	-
130	4	AU8	AV7	3	-
131	4	AT9	AW7	✓	-
132	4	AV8	AU9	✓	VREF
133	4	AW8	AT10	5	-
134	4	AV9	AU10	5	VREF
135	4	AW9	AT11	✓	-
136	4	AV10	AU11	✓	VREF
137	4	AW10	AU12	2	-
138	4	AV11	AT13	2	-
139	4	AW11	AU13	✓	VREF
140	4	AT14	AV12	✓	-
141	4	AU14	AW12	5	-
142	4	AT15	AV13	5	-
143	4	AU15	AW13	✓	-
144	4	AV14	AT16	✓	VREF
145	4	AW14	AU16	3	-
146	4	AV15	AR17	3	-
147	4	AW15	AT17	✓	-
148	4	AU17	AV16	✓	VREF
149	4	AR18	AW16	5	-
150	4	AT18	AV17	5	-
151	4	AU18	AW17	✓	-
152	4	AT19	AV18	✓	VREF
153	4	AU19	AW18	2	-

Table 23: FG680 Differential Pin Pair Summary
XCV600E, XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
154	4	AU21	AV19	2	VREF
155	5	AT21	AT22	NA	IO_LVDS_DLL
156	5	AV20	AR22	8	VREF
157	5	AV23	AW21	✓	VREF
158	5	AU23	AV21	✓	-
159	5	AT23	AW22	5	-
160	5	AR23	AV22	5	-
161	5	AV24	AW23	✓	VREF
162	5	AW24	AU24	✓	-
163	5	AW25	AT24	3	-
164	5	AV25	AU25	3	-
165	5	AW26	AT25	✓	VREF
166	5	AV26	AW27	✓	-
167	5	AU26	AV27	5	-
168	5	AT26	AW28	5	-
169	5	AU27	AV28	✓	-
170	5	AW29	AT27	✓	VREF
171	5	AW30	AU28	2	-
172	5	AV30	AV29	2	-
173	5	AW31	AU29	✓	VREF
174	5	AV31	AT29	✓	-
175	5	AW32	AU30	5	VREF
176	5	AW33	AT30	5	-
177	5	AV33	AU31	✓	VREF
178	5	AT31	AW34	✓	-
179	5	AV32	AV34	3	-
180	5	AU32	AW35	3	-
181	5	AT32	AV35	✓	VREF
182	5	AU33	AW36	✓	-
183	5	AT33	AV36	5	VREF
184	5	AU34	AU36	5	-
185	6	AT38	AR36	✓	-
186	6	AP36	AR38	6	-
187	6	AP37	AT39	4	VREF

**Table 29: FG1156 Differential Pin Pair Summary:
XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
32	0	B14	E14	3200 2600 2000 1600 1000	-
33	0	D14	G15	3200 2600 2000 1600 1000	VREF
34	0	D15	J16	3200 1600	-
35	0	B15	F15	3200 2000 1000	-
36	0	E15	A15	3200 2000 1000	-
37	0	A16	G16	3200 2600	-
38	0	J17	F16	3200 2600 2000 1600 1000	-
39	0	B16	C16	3200 2600 2000 1600 1000	VREF
40	0	A17	H17	2600 1600 1000	-
41	0	B17	G17	2600 1600 1000	VREF
42	1	J18	C17	None	IO_LVDS_DLL
43	1	C18	G18	2600 1600 1000	VREF
44	1	F18	H18	2600 1600 1000	-
45	1	A19	B19	3200 2600 2000 1600 1000	VREF
46	1	C19	K19	3200 2600 2000 1600 1000	-
47	1	E19	F19	3200 2600	-
48	1	J19	G19	3200 2000 1000	-
49	1	G20	A20	3200 2000 1000	-
50	1	F20	B20	3200 1600	-
51	1	E20	D20	3200 2600 2000 1600 1000	VREF

**Table 29: FG1156 Differential Pin Pair Summary:
XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
52	1	A21	H20	3200 2600 2000 1600 1000	-
53	1	J20	E21	3200	-
54	1	K20	D21	3200 2600 1000	-
55	1	H21	B21	3200 2600 1000	-
56	1	F21	G21	2000 1600	-
57	1	B22	A22	3200 2600 2000 1600 1000	VREF
58	1	C22	J21	3200 2600 2000 1600 1000	-
59	1	G22	D22	3200 2600 1000	-
60	1	A23	K21	3200 2000 1000	-
61	1	B23	F22	3200 2000 1000	-
62	1	H22	C23	3200 1600 1000	-
63	1	K22	D23	3200 2600 2000 1600 1000	-
64	1	J22	A24	3200 2600 2000 1600 1000	VREF
65	1	D24	H23	2600 1600 1000	-
66	1	E24	A25	2600 1600 1000	-
67	1	C25	A26	3200 2600 2000 1600 1000	VREF
68	1	B26	F24	3200 2600 2000 1600 1000	-
69	1	F25	K23	3200 2600	-
70	1	H24	C26	3200 2000 1000	VREF

**Table 29: FG1156 Differential Pin Pair Summary:
XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
311	7	P2	R8	2600 2000 1000	-
312	7	N1	R9	3200 2600 2000	-
313	7	R10	P4	3200 2600 1600 1000	-
314	7	N2	P8	3200 2600 2000 1600 1000	-
315	7	P7	P6	3200 2600 2000 1600	-
316	7	N4	M1	2600 2000 1000	VREF
317	7	N3	N6	3200 1600 1000	-
318	7	M2	P9	2600 1600	-
319	7	M3	N7	3200 2600 1600 1000	-
320	7	M4	P10	2000 1000	-
321	7	N8	L1	3200 2600 2000	-
322	7	N9	L2	3200 2600 2000 1600 1000	-
323	7	K1	M7	2000 1600 1000	VREF
324	7	L4	M8	3200 1600 1000	-
325	7	L5	J1	3200 2600 2000 1600 1000	-
326	7	K3	J2	3200 2600 2000 1600 1000	VREF
327	7	J3	L7	3200 2600 1600 1000	-
328	7	H2	M9	3200 2600 1600	-
329	7	K6	J4	2600 1000	VREF
330	7	G2	L8	3200 2600 2000 1600 1000	-

**Table 29: FG1156 Differential Pin Pair Summary:
XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
331	7	K7	H3	2000 1600	-
332	7	J5	G3	3200 2600 2000 1600 1000	VREF
333	7	H5	L9	2600 2000 1000	-
334	7	H4	J6	3200 2600 2000	-
335	7	K8	G4	3200 2600 1600 1000	-
336	7	F2	J7	3200 2600 2000 1600 1000	-
337	7	L10	F3	3200 2600 2000 1600	-
338	7	H6	E1	2600 2000 1000	VREF
339	7	E2	G5	3200 2600 1600 1000	-
340	7	D1	K9	2600 1600	-
341	7	J8	E3	3200 2600 1600 1000	VREF
342	7	D2	E4	2600 2000 1000	-
343	7	D3	F4	3200 2600 2000	-